MC100EPT23

Dual Differential LVPECL to LVTTL Translator

The MC100EPT23 is a dual differential LVPECL to LVTTL translator. Because LVPECL (Positive ECL) levels are used only +3.3V and ground are required. The small outline 8-lead SOIC package and the dual gate design of the EPT23 makes it ideal for applications which require the translation of a clock and a data signal.

The EPT23 is available in only the ECL 100K standard. Since there are no LVPECL outputs or an external VBB reference, the EPT23 does not require both ECL standard versions. The LVPECL inputs are differential. Therefore, the MC100EPT23 can accept any standard differential LVPECL input referenced from a VCC of +3.3V.

- 1.5ns Typical Propagation Delay
- Minimum Operating Frequency > 275MHz
- Differential LVPECL Inputs
- Small Outline SOIC Package
- 24mA LVTTL Outputs
- Flow Through Pinouts
- Internal Input Resistors: Pulldown on D, Pulldown and Pullup on \overline{D}
- Q Output will default LOW with inputs open or at GND
- ESD Protection: >1.2KV HBM, >150V MM
- Moisture Sensitivity Level 1, Indefinite Time Out of Drypack.
 For Additional Information, See Application Note AND8003/D
- Flammability Rating: UL-94 code V-0 @ 1/8", Oxygen Index 28 to 34
- Transistor Count = 91 devices

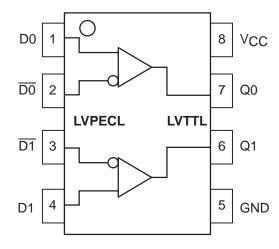


Figure 1. 8-Lead Pinout and Logic Diagram

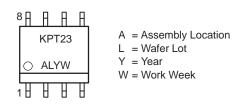


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MARKING DIAGRAM



*For additional information, see Application Note AND8002/D

PIN DESCRIPTION						
PIN FUNCTION						
Q0, Q1	LVTTL Outputs					
D0, D1, $\overline{\text{D0}}$, $\overline{\text{D1}}$ Differential LVPECL Inputs						
VCC	Positive Supply					
GND Ground						

ORDERING INFORMATION

Device	Package	Shipping
MC100EPT23D	SOIC	98 Units/Rail
MC100EPT23DR2	SOIC	2500 Tape & Reel

MC100EPT23

MAXIMUM RATINGS*

Symbol	Parameter	Value	Unit		
Vcc	Power Supply (GND = 0V)		0 to 3.8	VDC	
VI	Input Voltage (GND = 0V, V _I not more positive than	V _{CC})	0 to 3.8	VDC	
lout	Output Current	urrent Continuous Surge			
T _A	Operating Temperature Range		-40 to +85	°C	
T _{stg}	Storage Temperature		-65 to +150	°C	
θЈΑ	Thermal Resistance (Junction-to-Ambient)	Still Air 500lfpm	190 130	°C/W	
θЈС	Thermal Resistance (Junction-to-Case)	41 to 44 ± 5%	°C/W		
T _{sol}	Solder Temperature (<2 to 3 Seconds: 245°C desire	ed)	265	°C	

^{*} Maximum Ratings are those values beyond which damage to the device may occur.

DC CHARACTERISTICS (VCC = $3.3V \pm 0.3V$; GND = 0V; TA = $-40^{\circ}C$ to $85^{\circ}C$)

Symbol	Characteristic	Min	Тур	Max	Unit	
ICCH	Power Supply Current (Outputs set to HIGH)		10	18	25	mA
ICCL	Power Supply Current (Outputs set to LOW)		15	26	33	mA
VIH	Input HIGH Voltage (V _{CC} = 3.3) (Note 1.)		2135		2420	mV
VIL	Input LOW Voltage (V _{CC} = 3.3) (Note 1.)	Input LOW Voltage (V _{CC} = 3.3) (Note 1.)				mV
lН	Input HIGH Current				150	μΑ
IIL	Input LOW Current	D D	-150		0.5	μΑ
Vон	Output HIGH Voltage (I _{OH} = -3.0mA) (Note 2.)		2.4			V
VOL	Output LOW Voltage (I _{OL} = 24mA) (Note 2.)			0.5	V	
los	Output Short Circuit Current	-180		-50	mA	
VIHCMR	Input HIGH Voltage Common Mode Range (Note 3.)		2.0		3.3	V

NOTE: 100EP circuits are designed to meet the DC specifications shown in the above table after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse airflow greater than 500lfpm is maintained.

- All values vary 1:1 with V_{CC}.
 All loading with 500 ohms to GND, CL = 20pF.
- 3. VIHCMR min varies 1:1 with GND, max varies 1:1 with VCC.

AC CHARACTERISTICS ($V_{CC} = 3.3V \pm 0.3V$; GND = 0V)

		–40°C		25°C			85°C				
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
f _{max}	Maximum Toggle Frequency (Note 4.)	275	350		275	350		275	350		MHz
^t PLH [,] ^t PHL	Propagation Delay to Output Differential (Note 5.)	1.2 1.2	1.5 1.5	1.8 1.8	1.2 1.2	1.5 1.5	1.8 1.8	1.3 1.2	1.7 1.5	2.2 1.8	ns
tSK+ + tSK tSKPP	Output-to-Output Skew++ Output-to-Output Skew Part-to-Part Skew (Note 6.)		60 25 500			60 25 500			60 25 500		ps
^t JITTER	Cycle-to-Cycle Jitter		TBD			TBD			TBD		ps
V _{PP}	Input Voltage Swing (Differential) (Note 7.)	100	800	1200	100	800	1200	100	800	1200	mV
t _r t _f	Output Rise/Fall Times (20% – 80%) Q, $\overline{\mathbb{Q}}$	330	600	900	330	600	900	330	650	900	ps

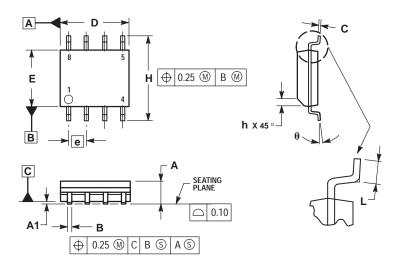
- 4. F_{max} guaranteed for functionality only. V_{OL} and V_{OH} levels are guaranteed at DC only.
 5. Reference (V_{CC} = 3.3V ± 5%; GND = 0V)
 6. Skew vare measured between outputs under identical conditions.

- 7. 200mV input guarantees full logic swing at the output.

MC100EPT23

PACKAGE DIMENSIONS

SO-8 **D SUFFIX** PLASTIC SOIC PACKAGE CASE 751-06 ISSUE T



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. DIMENSIONS ARE IN MILLIMETER.
 3. DIMENSION D AND E DO NOT INCLUDE MOLD PROTRUSION.
 4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
 5. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 TOTAL IN EXCESS OF THE B DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS							
DIM	MIN	MAX						
Α	1.35	1.75						
A1	0.10	0.25						
В	0.35	0.49						
С	0.19	0.25						
D	4.80	5.00						
Ε	3.80	4.00						
е	1.27	1.27 BSC						
Н	5.80	6.20						
h	0.25	0.50						
L	0.40	1.25						
θ	0°	7 °						

MC100FPT23

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